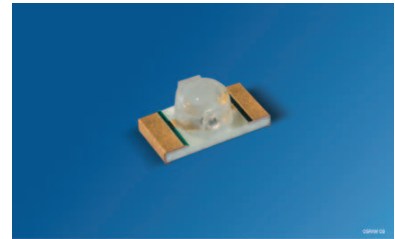


**IR-Lumineszenzdiode (850 nm) mit hoher Ausgangsleistung**  
**High Power Infrared Emitter (850 nm)**  
**Lead (Pb) Free Product - RoHS Compliant**

**SFH 4058**



**Wesentliche Merkmale**

- Sehr kleines Gehäuse:  
(LxBxH) 3.2 mm x 1.6mm x 1.1 mm
- Sehr hohe Gesamtleistung

**Anwendungen**

- Miniaturlichtschranken
- Industrieelektronik
- „Messen/Steuern/Regeln“
- Sensorik

**Sicherheitshinweise**

Je nach Betriebsart emittieren diese Bauteile hochkonzentrierte, nicht sichtbare Infrarot-Strahlung, die gefährlich für das menschliche Auge sein kann. Produkte, die diese Bauteile enthalten, müssen gemäß den Sicherheitsrichtlinien der IEC-Normen 60825-1 und 62471 behandelt werden.

**Features**

- Very small package:  
(LxWxH) 3.2 mm x 1.6 mm x 1.1 mm
- High optical total power

**Applications**

- Miniature photointerrupters
- Industrial electronics
- For drive and control circuits
- Sensor technology

**Safety Advices**

Depending on the mode of operation, these devices emit highly concentrated non visible infrared light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1 and IEC 62471.

<b>Typ Type</b>	<b>Bestellnummer Ordering Code</b>	<b>Strahlstärkegruppierung<sup>1)</sup> (<math>I_F = 70 \text{ mA}</math>, <math>t_p = 20 \text{ ms}</math>) Radiant Intensity Grouping<sup>1)</sup> <math>I_e \text{ (mW/sr)}</math></b>
SFH 4058	Q65110A9218	$\geq 6.3 \text{ (typ. 15)}$

<sup>1)</sup> gemessen bei einem Raumwinkel  $\Omega = 0.01 \text{ sr}$  / measured at a solid angle of  $\Omega = 0.01 \text{ sr}$

**Grenzwerte** ( $T_A = 25\text{ °C}$ )**Maximum Ratings**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{op}, T_{stg}$	- 40 ... + 85	°C
Sperrspannung Reverse voltage	$V_R$	5	V
Vorwärtsgleichstrom Forward current	$I_F$	70	mA
Stoßstrom, $t_p = 10\ \mu\text{s}$ , $D = 0$ Surge current	$I_{FSM}$	700	mA
Verlustleistung Power dissipation	$P_{tot}$	140	mW
Wärmewiderstand Sperrschicht - Umgebung bei Montage auf FR4 Platine, Padgröße je $5\ \text{mm}^2$ Thermal resistance junction - ambient mounted on PC-board (FR4), pads size $5\ \text{mm}^2$ each	$R_{thJA}$	540	K/W
Wärmewiderstand Sperrschicht - Lötstelle bei Montage auf Metall-Block Thermal resistance junction - soldering point, mounted on metal block	$R_{thJS}$	360	K/W

**Kennwerte** ( $T_A = 25\text{ °C}$ )**Characteristics**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Wellenlänge der Strahlung Wavelength at peak emission $I_F = 70\ \text{mA}$ , $t_p = 10\ \text{ms}$	$\lambda_{peak}$	860	nm
Schwerpunkts-Wellenlänge der Strahlung Centroid Wavelength $I_F = 70\ \text{mA}$ , $t_p = 10\ \text{ms}$	$\lambda_{centroid}$	850	nm
Spektrale Bandbreite bei 50% von $I_{max}$ Spectral bandwidth at 50% of $I_{max}$ $I_F = 70\ \text{mA}$ , $t_p = 10\ \text{ms}$	$\Delta\lambda$	42	nm
Abstrahlwinkel Half angle	$\varphi$	$\pm 40$	Grad deg.
Aktive Chipfläche Active chip area	$A$	0.04	$\text{mm}^2$

Kennwerte ( $T_A = 25\text{ °C}$ )

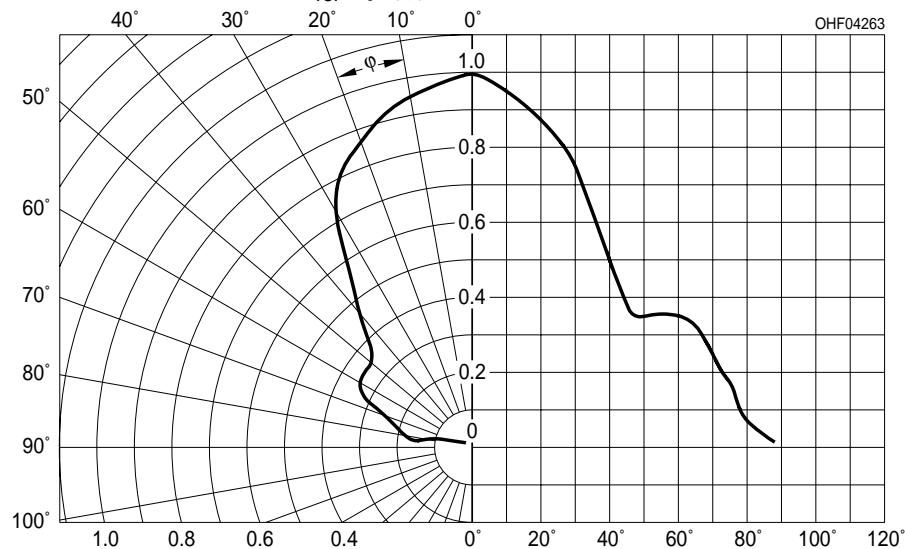
Characteristics (cont'd)

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Abmessungen der aktiven Chipfläche Dimension of the active chip area	$L \times B$ $L \times W$	$0.2 \times 0.2$	mm <sup>2</sup>
Schaltzeiten, $I_e$ von 10% auf 90% und von 90% auf 10%, bei $I_F = 70\text{ mA}$ , $R_L = 50\ \Omega$ Switching times, $I_e$ from 10% to 90% and from 90% to 10%, $I_F = 70\text{ mA}$ , $R_L = 50\ \Omega$	$t_r$ , $t_f$	10	ns
Durchlassspannung Forward voltage $I_F = 70\text{ mA}$ , $t_p = 20\text{ ms}$	$V_F$	1.6 (< 2.0)	V
Sperrstrom Reverse current	$I_R$	not designed for reverse operation	$\mu\text{A}$
Gesamtstrahlungsfluss Total radiant flux $I_F = 70\text{ mA}$ , $t_p = 20\text{ ms}$	$\Phi_{e\text{ typ}}$	33	mW
Temperaturkoeffizient von $I_e$ bzw. $\Phi_e$ , $I_F = 70\text{ mA}$ Temperature coefficient of $I_e$ or $\Phi_e$ , $I_F = 70\text{ mA}$	$TC_I$	- 0.5	%/K
Temperaturkoeffizient von $V_F$ , $I_F = 70\text{ mA}$ Temperature coefficient of $V_F$ , $I_F = 70\text{ mA}$	$TC_V$	- 0.7	mV/K
Temperaturkoeffizient von $\lambda$ , $I_F = 70\text{ mA}$ Temperature coefficient of $\lambda$ , $I_F = 70\text{ mA}$	$TC_\lambda$	+ 0.3	nm/K

**Strahlstärke  $I_e$  in Achsrichtung<sup>1)</sup>**gemessen bei einem Raumwinkel  $\Omega = 0.01$  sr**Radiant Intensity  $I_e$  in Axial Direction**at a solid angle of  $\Omega = 0.01$  sr

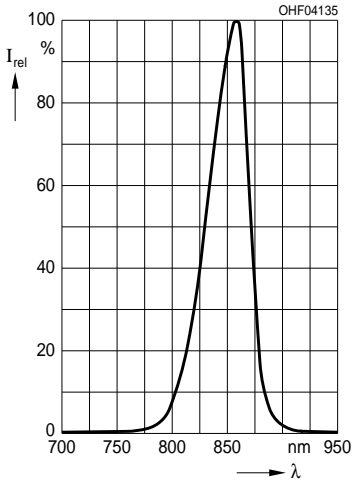
Bezeichnung Parameter	Symbol	Werte Values			Einheit Unit
		SFH 4058			
		-Q	-R	-S	
Strahlstärke Radiant intensity $I_F = 70$ mA, $t_p = 20$ ms	$I_{e \min}$ $I_{e \max}$	6.3 12.5	10 20	16 32	mW/sr mW/sr
Strahlstärke Radiant intensity $I_F = 500$ mA, $t_p = 25$ $\mu$ s	$I_{e \text{ typ}}$	36	55	90	mW/sr

<sup>1)</sup> Nur eine Gruppe in einer Verpackungseinheit (Streuung kleiner 2:1) /  
Only one bin in one packing unit (variation lower 2:1)

**Abstrahlcharakteristik****Radiation Characteristics  $I_{\text{rel}} = f(\varphi)$** 

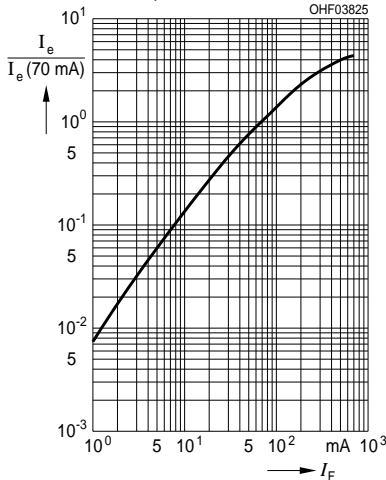
**Relative Spectral Emission**

$I_{rel} = f(\lambda)$



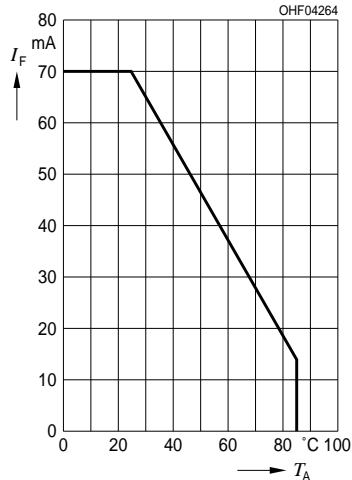
**Radiant Intensity**  $\frac{I_e}{I_e(70 \text{ mA})} = f(I_F)$

Single pulse,  $t_p = 25 \mu\text{s}$



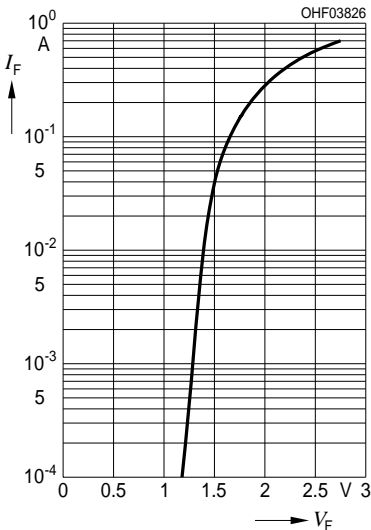
**Max. Permissible Forward Current**

$I_F = f(T_A), R_{thJA} = 540 \text{ K/W}$



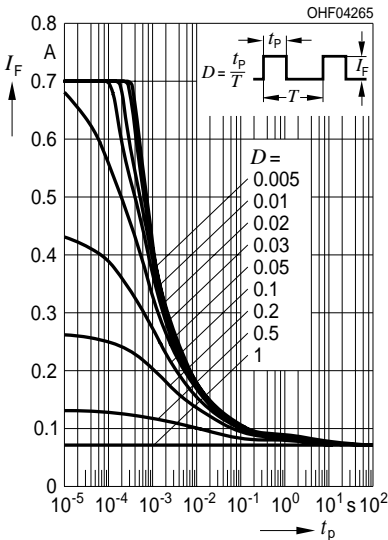
**Forward Current**  $I_F = f(V_F)$

Single pulse,  $t_p = 100 \mu\text{s}$



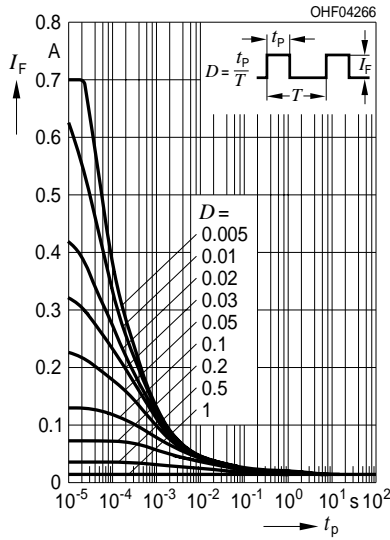
**Permissible Pulse Handling Capability**

$I_F = f(\tau), T_A = 25 \text{ }^\circ\text{C}$ ,  
duty cycle  $D =$  parameter

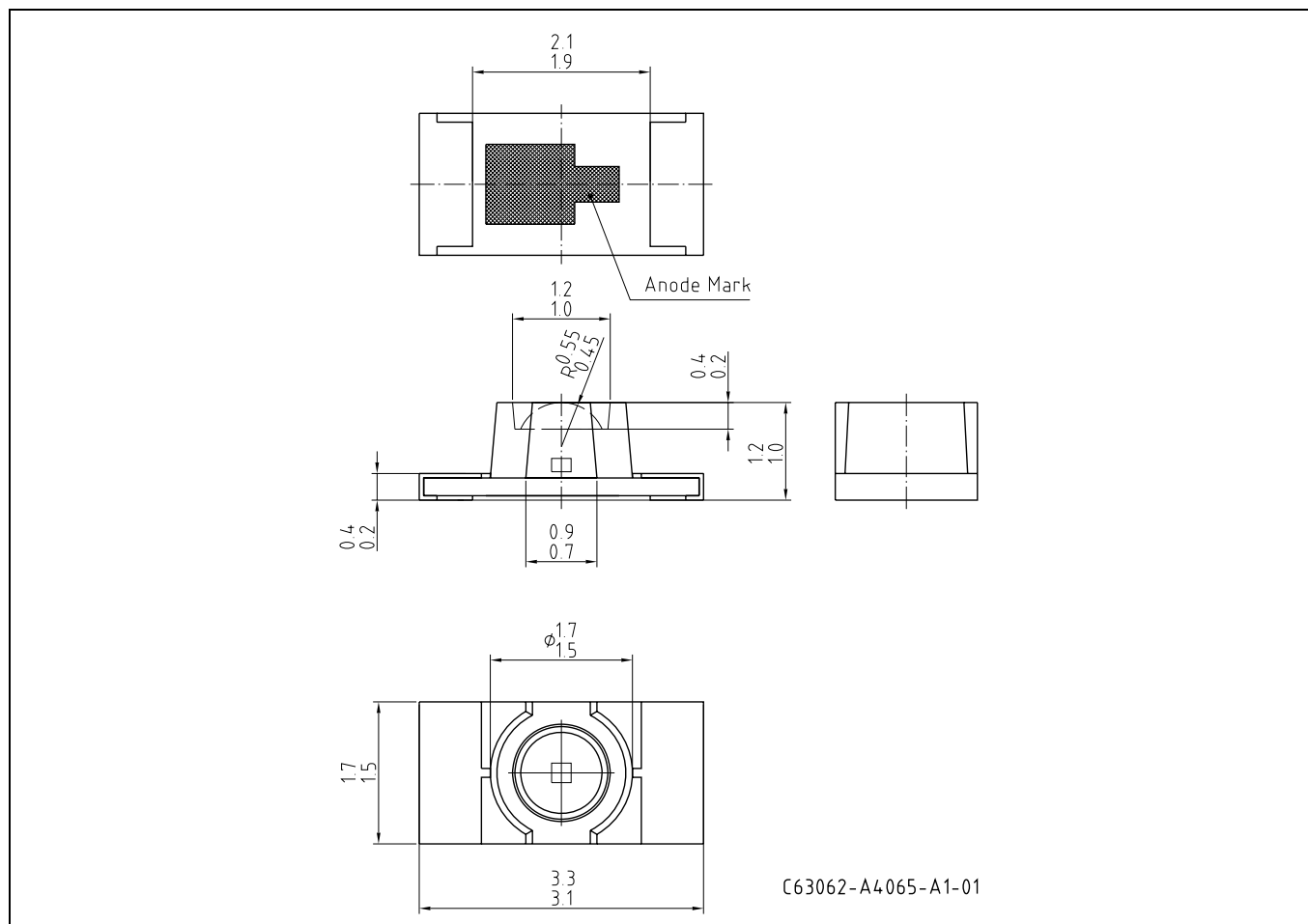


**Permissible Pulse Handling Capability**

$I_F = f(\tau), T_A = 85 \text{ }^\circ\text{C}$ ,  
duty cycle  $D =$  parameter



## Maßzeichnung Package Outlines



Maße in mm/ Dimensions in mm.

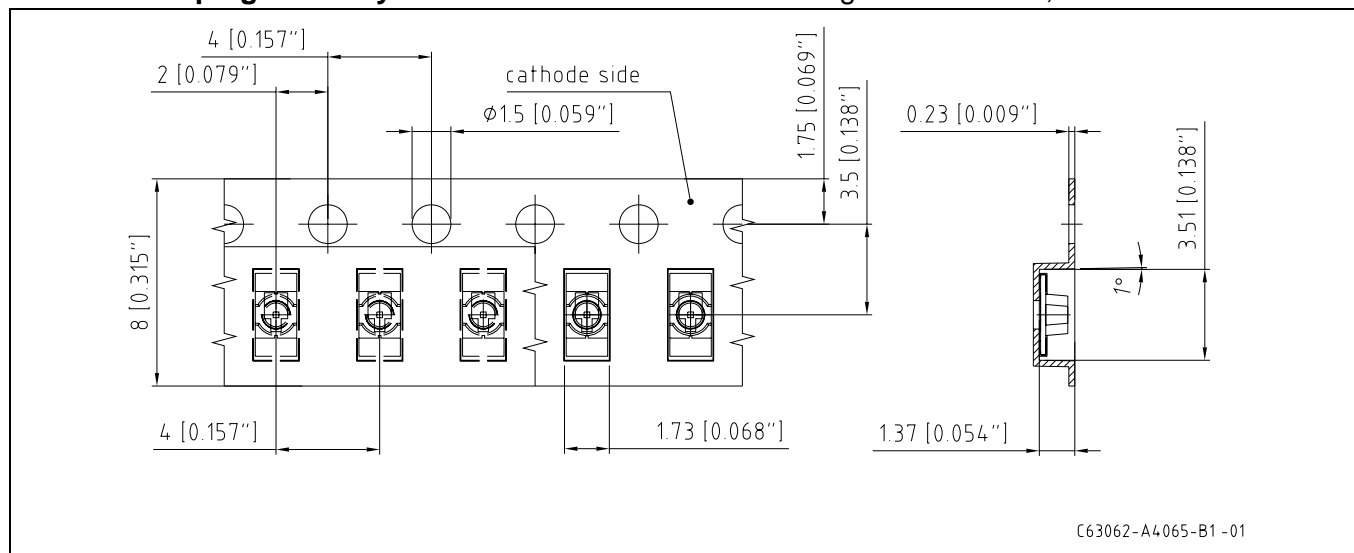
Gehäuse / Package	Chip LED/ Chip LED
Farbe / Colour	Farblos klar / colourless clear
Gehäusemarkierung/ Package marking	Anode / anode

**Gurtung / Polarität und Lage**

Verpackungseinheit 2000/Rolle, ø180 mm

**Method of Taping / Polarity and Orientation**

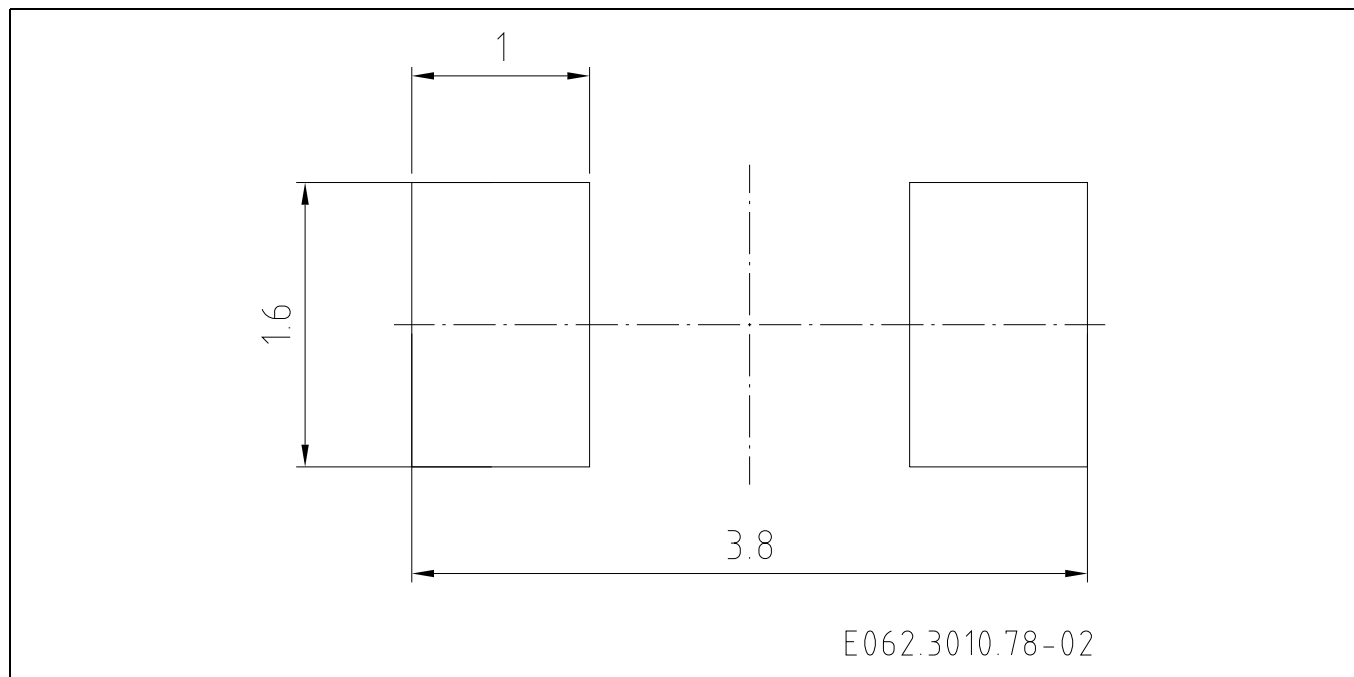
Packing unit 2000/reel, ø180 mm



Maße in mm (inch) / Dimensions in mm (inch).

**Empfohlenes Lötpaddesign  
Recommended Solder Pad**

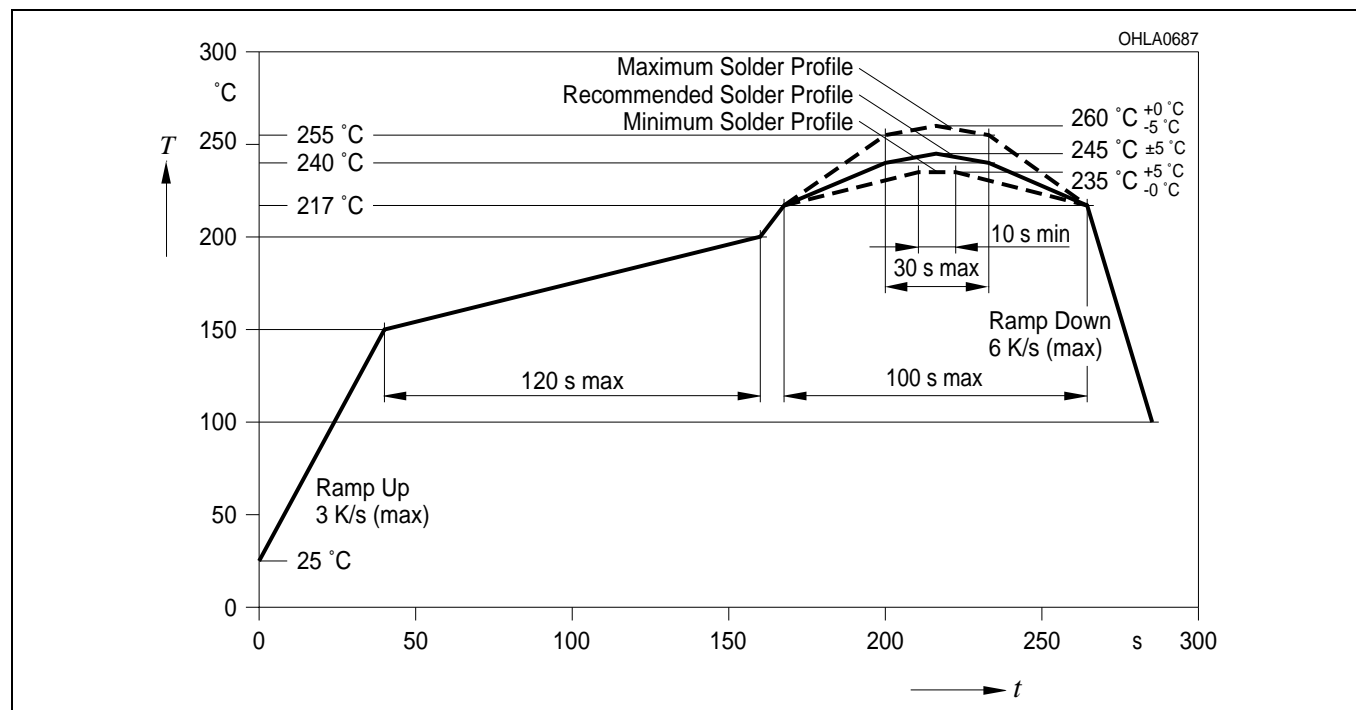
Reflow Löten  
Reflow Soldering



Maße in mm / Dimensions in mm.

**Lötbedingungen**  
**Soldering Conditions**  
**Reflow Lötprofil für bleifreies Löten**  
**Reflow Soldering Profile for lead free soldering**

Vorbehandlung nach JEDEC Level 3  
 Preconditioning acc. to JEDEC Level 3  
 (nach J-STD-020C)  
 (acc. to J-STD-020C)



Published by  
**OSRAM Opto Semiconductors GmbH**  
 Leibnizstrasse 4, D-93055 Regensburg  
[www.osram-os.com](http://www.osram-os.com)

© All Rights Reserved.

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances. For information on the types in question please contact our Sales Organization.

#### Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

**Components used in life-support devices or systems must be expressly authorized for such purpose!** Critical components<sup>1</sup>, may only be used in life-support devices or systems<sup>2</sup> with the express written approval of OSRAM OS.

<sup>1</sup> A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or effectiveness of that device or system.

<sup>2</sup> Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health of the user may be endangered.

EU RoHS and China RoHS compliant product



此产品符合欧盟 RoHS 指令的要求；

按照中国的相关法规和标准，不含有毒有害物质或元素。



# Mouser Electronics

## Related Product Links

[720-SFH4058 - Osram Opto Semiconductor SFH 4058](#)